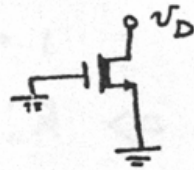


28 $k_n'(W/L) = 2 \text{ mA/V}^2$

$$V_t = -3 \text{ V}$$

$$V_{GS} = 0 > V_t \Rightarrow \text{device is on}$$

$$V_{GS} - V_t = 3 \text{ V}$$



(a) $V_D = 0.1 \text{ V}$ $V_{DS} = 0.1 \text{ V} < V_{GS} - V_t$

\Rightarrow triode region

$$i_D = k_n' \frac{W}{L} \left[(V_{GS} - V_t) V_{DS} - \frac{1}{2} V_{DS}^2 \right]$$
$$= 2 \left[3 \times 0.1 - \frac{1}{2} \times 0.1^2 \right] = \underline{\underline{0.59 \text{ mA}}}$$

(b) $V_D = 1 \text{ V}$ $V_{DS} = 1 \text{ V} < V_{GS} - V_t$

\Rightarrow triode region,

$$i_D = 2 \left[3 \times 1 - \frac{1}{2} \times 1^2 \right] = \underline{\underline{5 \text{ mA}}}$$

(c) $V_D = 3 \text{ V}$ $V_{DS} = 3 \text{ V} = V_{GS} - V_t$

\Rightarrow saturation region,

$$i_D = \frac{1}{2} k_n' \frac{W}{L} (V_{GS} - V_t)^2$$
$$= \frac{1}{2} \times 2 \times 9 = \underline{\underline{9 \text{ mA}}}$$

(d) $V_D = 5 \text{ V}$ $V_{DS} = 5 \text{ V} > V_{GS} - V_t$

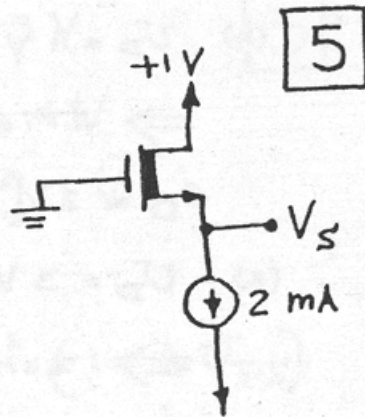
\Rightarrow saturation region,

$$i_D = \frac{1}{2} \times 2 \times 9 = \underline{\underline{9 \text{ mA}}}$$

31 $k_n' \frac{W}{L} = 4 \text{ mA/V}^2$

$V_t = -2 \text{ V}$

Since $V_{DG} < |V_t|$, the MOSFET will be operating in the triode region,



$$I_D = k_n' \frac{W}{L} \left[(V_{GS} - V_t) V_{DS} - \frac{1}{2} V_{DS}^2 \right]$$

$$2 = 4 \left[(-V_S + 2)(1 - V_S) - \frac{1}{2} (1 - V_S)^2 \right]$$

$$= -4V_S + 8 - 8V_S + 4V_S^2 - 2 + 2V_S^2 + 4V_S$$

$$2V_S^2 - 8V_S + 4 = 0$$

$$V_S^2 - 4V_S + 2 = 0$$

$$V_S = \frac{4 \pm \sqrt{16 - 8}}{2} = 2 \pm \sqrt{2}$$

$$= 3.414 \text{ V or } 0.586 \text{ V}$$

The first answer is not physically meaningful for it results in $V_{GS} = -3.414 < V_t$ and thus implies cut-off. Thus

$$V_S = \underline{\underline{+0.586 \text{ V}}}$$

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$$I_D = \frac{1}{2} k_n' \frac{W}{L} (V_{GS} - V_t)^2$$

$$1 = \frac{1}{2} k_n' \frac{W}{L} (-1 - V_t)^2 \quad (1)$$

$$9 = \frac{1}{2} k_n' \frac{W}{L} (1 - V_t)^2 \quad (2)$$

$$\frac{(2)}{(1)} \Rightarrow 9 = \frac{(1 - V_t)^2}{(-1 - V_t)^2} \Rightarrow 3 = \frac{1 - V_t}{-1 - V_t}$$

$$V_t = \underline{\underline{-2V}}$$

Substitute in (1)

$$1 = \frac{1}{2} k_n' \frac{W}{L} \times 1$$

$$k_n' \frac{W}{L} = 2 \text{ mA/V}^2$$

$$I_{DSS} = \frac{1}{2} k_n' \frac{W}{L} V_t^2 = \frac{1}{2} \times 2 \times 4 = \underline{\underline{4 \text{ mA}}}$$

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